

4A 3Quadrants TRIACs

Product Summary

Symbol	Value	Unit
$I_{T(AV)}$	4	A
$V_{DRM} V_{RRM}$	600/800	V
V_{TM}	1.55	V

Features

With high ability to withstand the shock loading of large current, With high commutation performances, 3 quadrants products especially recommended for use on inductive load.

Application

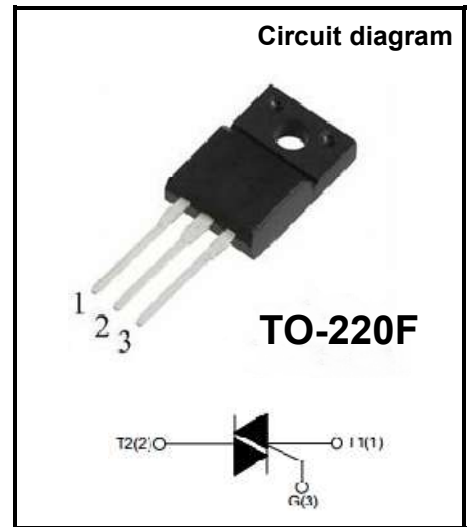
Washing machine, vacuums, massager, solid state relay, AC Motor speed regulation and so on.

Order Information

Part Number	Package	Marking	Packing	Packing Quantity
BTA04F	TO-220F	BTA04F XXXX	box	1000PCS/box

Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Repetitive peak off-state voltage	V_{DRM}	600/800	V
Repetitive peak reverse voltage	V_{RRM}	600/800	V
RMS on-state current	$I_T(RMS)$	4	A
Non repetitive surge peak on-state current (full cycle, F=50Hz)	I_{TSM}	40	A
I^2t value for fusing (tp=10ms)	I^2t	8	A ² s
Critical rate of rise of on-state current ($I_G = 2 \times I_{GT}$)	di/dt	I - II - III 50	A/ μ s
Peak gate current	I_{GM}	4	A
Average gate power dissipation	$P_G (AV)$	1	W
Junction Temperature	T_J	-40~+125	°C
Storage Temperature	T_{STG}	-40 ~+150	°C



Electrical characteristics (TA=25°C, unless otherwise noted)

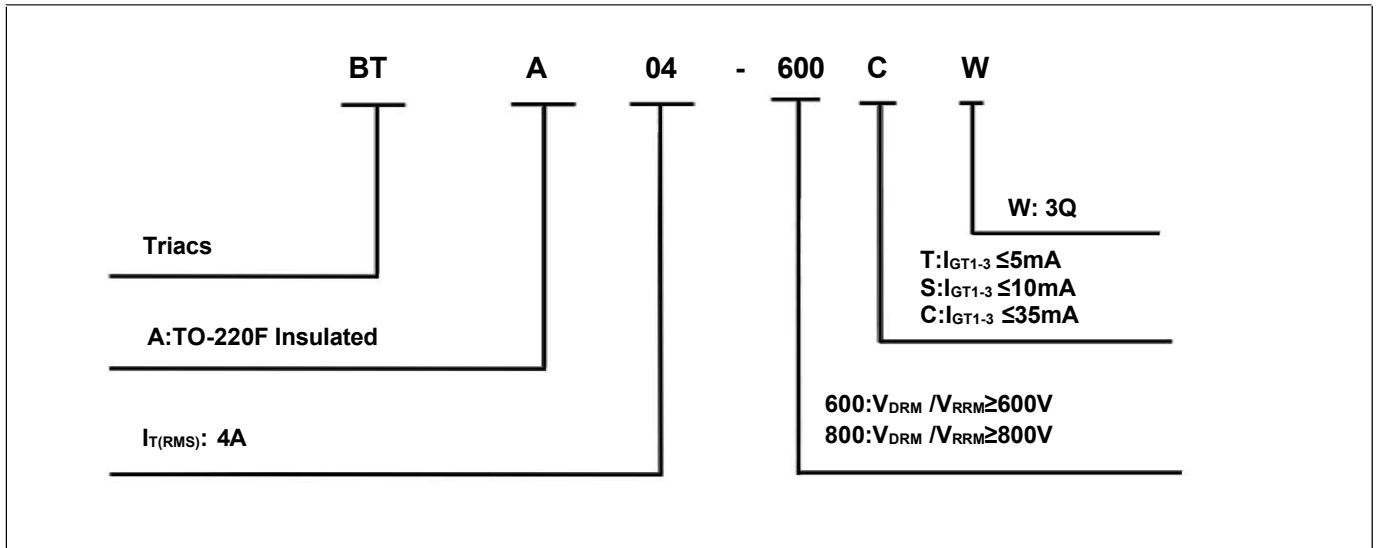
Parameter	Symbol	Test Condition	Value			Unit	
			TW	SW	CW		
Gate trigger current	I_{GT}	$V_D=12V$ $R_L=33\Omega$ $T_J=25^\circ C$	I-II-III	≤ 5	≤ 10	≤ 35	mA
Gate trigger voltage	V_{GT}	$T_J=25^\circ C$	I-II-III	≤ 1.3			V
Gate non-trigger voltage	V_{GD}	$V_D = V_{DRM}$ $T_J=125^\circ C$		≥ 0.2			V
latching current	I_L	$I_G=1.2I_{GT}$	I-III-IV	≤ 10	≤ 25	≤ 50	mA
			II	≤ 15	≤ 30	≤ 60	
Holding current	I_H	$I_T = 100mA$		≤ 10	≤ 15	≤ 35	mA
Critical-rate of rise of commutation voltage	dV_D/dt	$V_D=67\%V_{DRM}$ Gate Open $T_J=125^\circ C$		≥ 20	≥ 40	≥ 400	V/μs

STATIC CHARACTERISTICS

Forward "on" voltage	V_{TM}	$I_{TM} = 6A$ $t_p=380\mu s$		≤ 1.55			V
Repetitive Peak Off-State Current	I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$	$T_J=25^\circ C$	≤ 5	≤ 5	≤ 5	μA
Repetitive Peak Reverse Current	I_{RRM}		$T_J=125^\circ C$	≤ 0.5	≤ 0.5	≤ 0.5	mA

THERMAL RESISTANCES

Thermal resistance	$R_{th(j-c)}$	Junction to case(AC)		3.3			$^\circ C/W$
	$R_{th(j-a)}$	Junction to ambient		60			$^\circ C/W$

Ordering Information


Typical Characteristics

FIG.1: Maximum power dissipation versus RMS on-state current (full cycle)

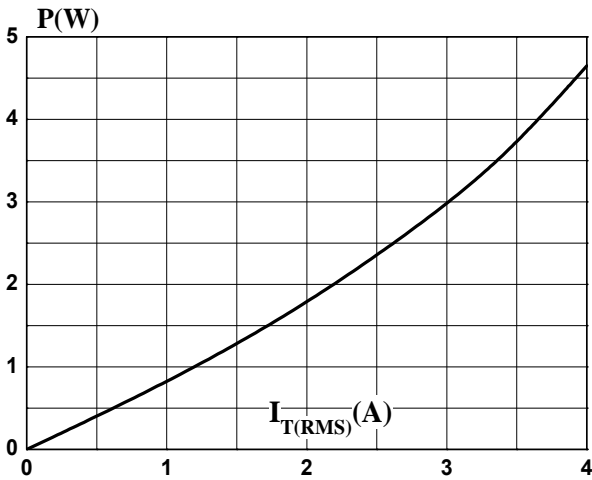


FIG.3: Surge peak on-state current versus number of cycles

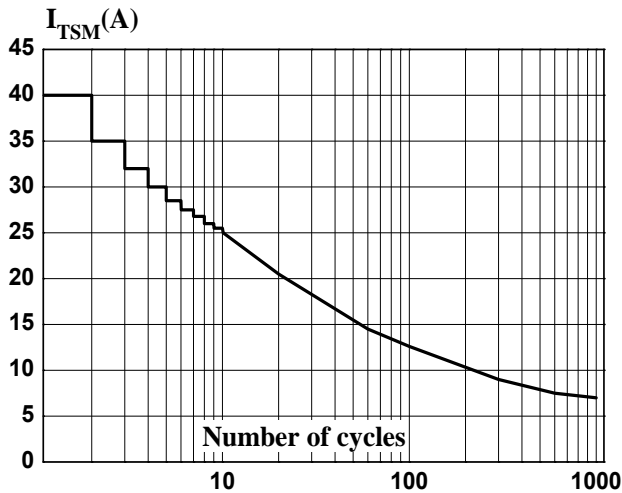


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10\text{ms}$

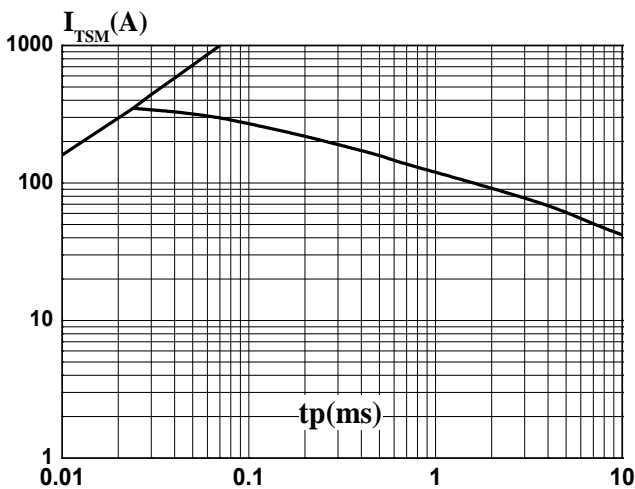


FIG.2: RMS on-state current versus case temperature (full cycle)

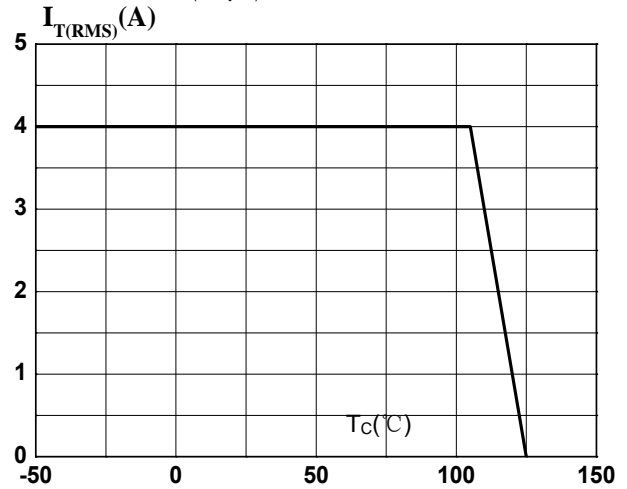


FIG.4: On-state characteristics (maximum values)

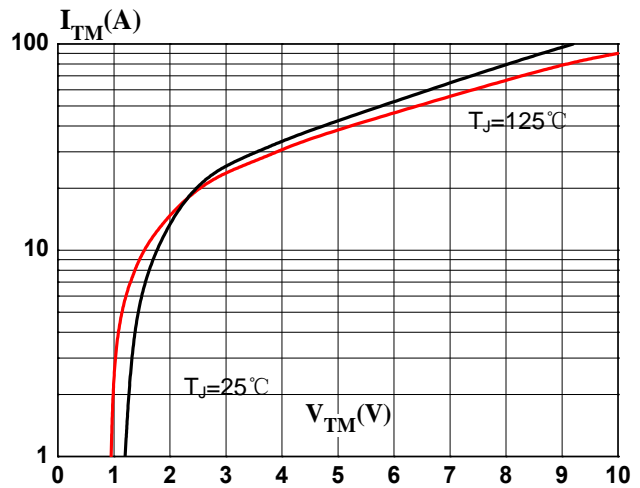
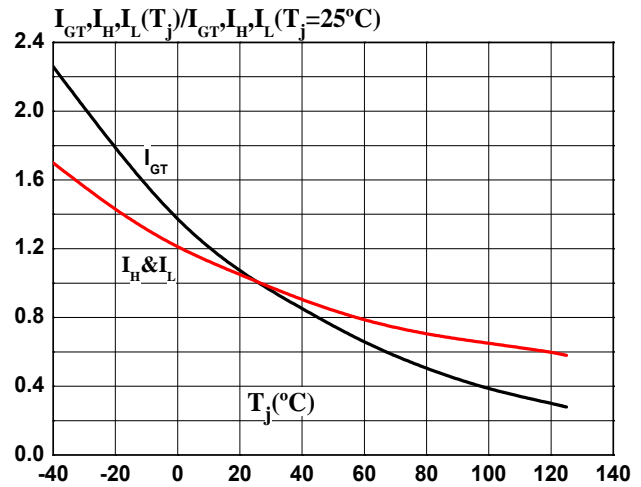
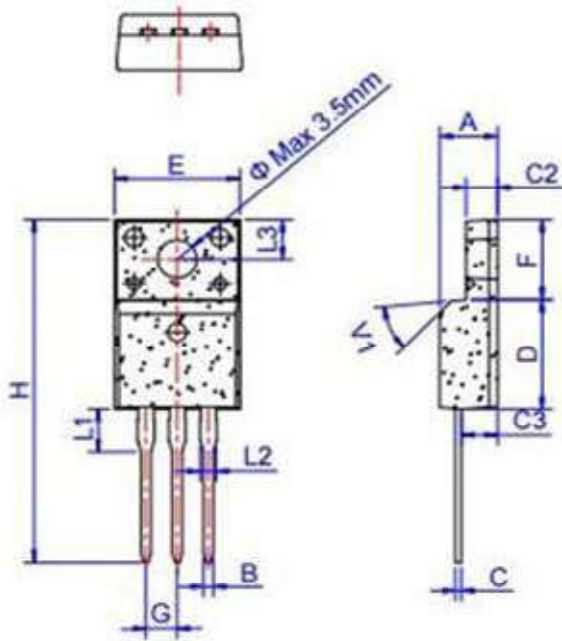


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature (typical values)



TO-220F(Ins)



TO-220F Ins

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.80	0.173		0.189
B	0.74	0.80	0.83	0.029	0.031	0.033
C	0.48		0.75	0.019		0.030
C2	2.40		2.70	0.094		0.106
C3	2.60		3.00	0.102		0.118
D	8.80		9.30	0.346		0.366
E	9.70		10.3	0.382		0.406
F	6.40		7.00	0.252		0.276
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.63			0.143	
L2	1.14		1.70	0.045		0.067
L3		3.30			0.130	
V1		45°			45°	